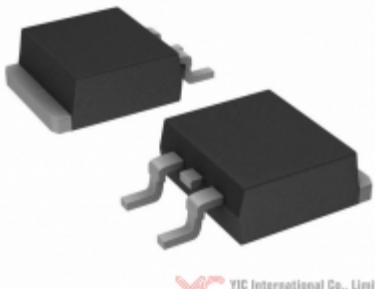









	<h2 style="color: #C00000;">IPB100N06S3-03</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">IPB100N06S3-03</a>
	<b>Hersteller / Marke:</b>	<a href="#">International Rectifier (Infineon Technologies)</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 55V 100A D2PAK
<b>Datenblätter:</b>	 <a href="#">IPB100N06S3-03.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 9000 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	IPB100N06S3-03
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 55V 100A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	9000 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	300W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V <sub>dss</sub> )	55V
Strom - Ununterbrochener Abfluss (I <sub>d</sub> ) bei 25 °C	100A (Tc)
R <sub>ds On</sub> (Max) @ I <sub>d</sub> , V <sub>gs</sub>	3 mOhm @ 80A, 10V
V <sub>GS</sub> (th) (Max) @ I <sub>d</sub>	4V @ 230μA
Gate Charge (Q <sub>g</sub> ) (Max) @ V <sub>gs</sub>	480nC @ 10V
Eingabekapazität (C <sub>iss</sub> ) (Max) @ V <sub>ds</sub>	21620pF @ 25V
Verpackung	Tape & Reel (TR)

IPB100N06S3-03 ist neu im Original, Suche IPB100N06S3-03 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB100N06S3-03 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB100N06S3-03: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>IPB100N08S207ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>	 <p><b>IPB100N06S2L05ATMA2</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3</p>	 <p><b>IPB100N06S3</b> Original TO-263</p>	 <p><b>IPB100N08S2-07</b> INFINEO IPB100N08S2-07 INFINEO</p>
 <p><b>IPB100N06S3-04</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO-263</p>	 <p><b>IPB100N06S3L-04</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO-263</p>	 <p><b>IPB100N06S205ATMA4</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3</p>	 <p><b>IPB100N06S2L05ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3</p>

### heiße Teile

Mehr

⊗ IPB08CN10NG	↔ IPB08CNE8N	⇒ IPB08CNE8NG	D IPB090N06N3	↔ IPB090N06N3G
⊣ IPB091N06NG	⊗ IPB093N04LG	D IPB096N03L	⇒ IPB096N03LG	↔ IPB097N08N3
⊗ IPB097N08N3G	⊣ IPB09N03	⊗ IPB09N03LA	↔ IPB09N03LAG	↔ IPB09N03LAT
D IPB100N04S2-04	⊗ IPB100N04S2L-03	⊣ IPB100N04S3	⊗ IPB100N04S3-03	↔ IPB100N04S3-03M
⇒ IPB100N04S4-02D	↔ IPB100N04S4-03D	⊗ IPB100N04S4-H2	⊣ IPB100N06S2-05	↔ IPB100N06S2L-05
↔ IPB100N06S3-04	⇒ IPB100N06S3L-03	D IPB100N06S3L-04	⊗ IPB100N08S2-07	⊣ IPB100N08S2L-07
⊗ IPB100N10S3-05	D IPB107N20N3G	⇒ IPB10N03L	↔ IPB10N03LB	↔ IPB10N03LBG
⊣ IPB110N06L	⊗ IPB110N06LG	↔ IPB114N03L	⇒ IPB114N03LG	↔ IPB11N03LAG
⊗ IPB11N60S5	⊣ IPB120N04S3-02	⊗ IPB120N04S4-01	D IPB120N04S4-02	↔ IPB120N06NG
↔ IPB120N06S4	⊗ IPB120N06S4-02	⊣ IPB120N06S4-03	⊗ IPB120N06S4-H1	↔ IPB120P04L03

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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